#### Application

 $\cdot$  Converter

ROHM

- · Photovoltaics, wind power generation.
- · Induction heating equipment.

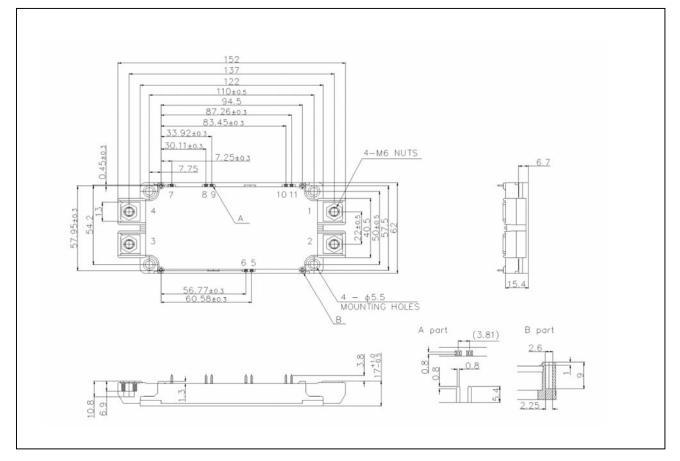
#### Features

- 1) Low surge, low switching loss.
- 2) High-speed switching possible.
- 3) Reduced temperature dependence.

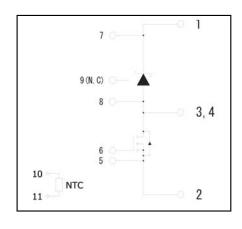
#### Construction

This product is a chopper module consisting of SiC-DMOSFET and SiC-SBD from ROHM.

#### •Dimensions & Pin layout (Unit : mm)



## Circuit diagram



#### • Absolute maximum ratings $(T_i = 25^{\circ}C)$

Parameter	Symbol	Conditions	Limit	Unit	
Drain-source voltage	V <sub>DSS</sub>	G-S short	1200		
Repetitive reverse voltage	V <sub>DSS</sub>	Clamp diode	1200	V	
Gate-source voltage(+)	V <sub>GSS</sub>	D-S short	22		
Gate-source voltage(-)			-6		
G - S Voltage (t <sub>surge</sub> <300nsec)	$V_{GSS\_surge}$	D-S short	-10 to 26		
	I <sub>D</sub>	DC (T <sub>c</sub> =60°C)	204		
Drain current * <sup>1</sup>	I <sub>DRM</sub>	Pulse (T <sub>c</sub> =60°C) 1ms * <sup>2</sup>	360		
	I <sub>DRM</sub>	Pulse (T <sub>c</sub> =60°C) 10us * <sup>2</sup> * <sup>3</sup> 54		1	
	ا_S	DC (T <sub>c</sub> =60°C ) V <sub>GS</sub> =18V	204		
Source current *1	I <sub>SRM</sub>	Pulse (Tc=60°C) 1ms V <sub>GS</sub> =18V * <sup>2</sup> 360		А	
	I <sub>SRM</sub>	Pulse (Tc=60°C) 10us V <sub>GS</sub> =18V * <sup>2</sup> * <sup>3</sup>	540		
	I <sub>F</sub>	DC (T <sub>c</sub> =60°C )	204	)	
Forward current (clamp diode) *1	I <sub>FRM</sub>	Pulse (Tc=60°C) 1ms * <sup>2</sup>	360		
	I <sub>FRM</sub>	Pulse (Tc=60°C) 10us *2 *3	540		
Total power dissipation * <sup>3</sup>	Ptot	T <sub>c</sub> =25°C	1360	W	
Max Junction Temperature	T <sub>jmax</sub>		175		
Operating junction temperature	T <sub>jop</sub>		-40 to150	°C	
Storage temperature	T <sub>stg</sub>		-40 to125	1	
Isolation voltage	Visol	Terminals to baseplate, f=60Hz AC 1min.	2500	Vrms	
Mounting to rough		Main Terminals : M6 screw	4.5	– N · m	
Mounting torque	_	Mounting to heat shink : M5 screw	3.5		

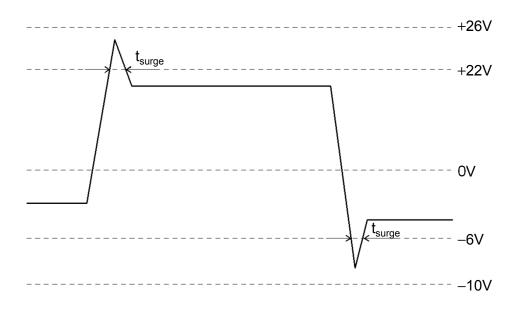
(\*1) Case temperature ( $T_c$ ) is defined on the surface of base plate just under the chips.

(\*2) Repetition rate should be kept within the range where temperature rise if die should not exceed  $T_{j max}$ .

(\*3) Please use an appropriate external gate resistor not to exceed maximum ratings of Drain - Source Voltage.

(\*4)  $T_j\,$  is less than 175°C

Example of acceptable V<sub>GS</sub> waveform



#### •Electrical characteristics (T<sub>i</sub>=25°C)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
On state stati-	V <sub>DS(on)</sub>	I <sub>D</sub> =180A, V <sub>GS</sub> =18V	T <sub>j</sub> =25°C	-	2.2	3.2	V
On-state static			T <sub>j</sub> =125°C	-	3.1	-	
Drain-Source Voltage			T <sub>i</sub> =150°C	-	3.5	5.0	
Drain cutoff current	I <sub>DSS</sub>	V <sub>DS</sub> =1200V, V <sub>GS</sub> =0V		-	-	10	μA
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> =180A	T <sub>j</sub> =25°C	-	1.6	2.2	V
			T <sub>j</sub> =125°C		2.0	-	
			T <sub>i</sub> =150°C	-	2.2	3.3	
Reverse current	I <sub>RRM</sub>	Clamp diode		-	-	3.2	mA
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =35.2mA		1.6	-	4	V
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =22V, V <sub>DS</sub> =0V		-	-	0.5	μΑ
		V <sub>GS</sub> = -6V, V <sub>DS</sub> =0V		-0.5	-	-	
Switching Characteristics	t <sub>d(on)</sub>	V <sub>GS(on)</sub> =18V, V <sub>GS(off)</sub> =0V		-	49	-	ns
	t <sub>r</sub>	V <sub>DS</sub> =600V		-	36	-	
	t <sub>rr</sub>	$I_D$ =180A R <sub>G(on)</sub> =1.0 $\Omega$ , R <sub>G(off)</sub> =0.2 $\Omega$ inductive load		-	20	-	
	t <sub>d(off)</sub>			-	139	-	
	t <sub>f</sub>			-	32	-	
Input Capacitance	Ciss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, 200kHz		-	20	-	nF
Gate Registance	R <sub>Gint</sub>	T <sub>i</sub> =25°C		-	1.2	-	Ω
NTC Rated Resistance	R25	Ĺ.			5.0		kΩ
NTC B Value	B50/25				3370		K
Stray Inductance	Ls				13.0	-	nH
Creepage Distance	-	Terminal to heat sink			14.5	-	mm
		Terminal to terminal			15.0	-	mm
	-	Terminal to heat sink			12.0	-	mm
Clearance Distance		Terminal to terminal			9.0	-	mm
Junction-to-Case Thermal		DMOSFET (1/2 module) * <sup>5</sup>		-	-	0.11	K/W
Resistance		SBD (1/2 module) * <sup>5</sup>		-	-	0.14	
Case-to -heat sink	D (of)	Case to heat sink, per 1 module, Thermal grease appied * <sup>6</sup>		-	0.035		
Thermal Resistance	R <sub>th</sub> (c-f)					-	

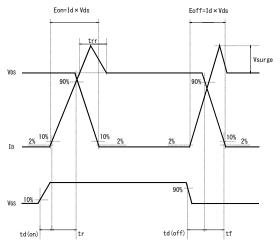
(\*5) Measurement of  $T_c$  is to be done at the point just beneath the chip.

(\*6) Typical value is measured by using thermally conductive grease of  $\lambda$ =0.9W/(m·K).

(\*7) If the Product is used beyond absolute maximum ratings defined in the Specifications,

as its internal structure may be damaged, please replace such Product with a new one.

#### •Waveform for switching test



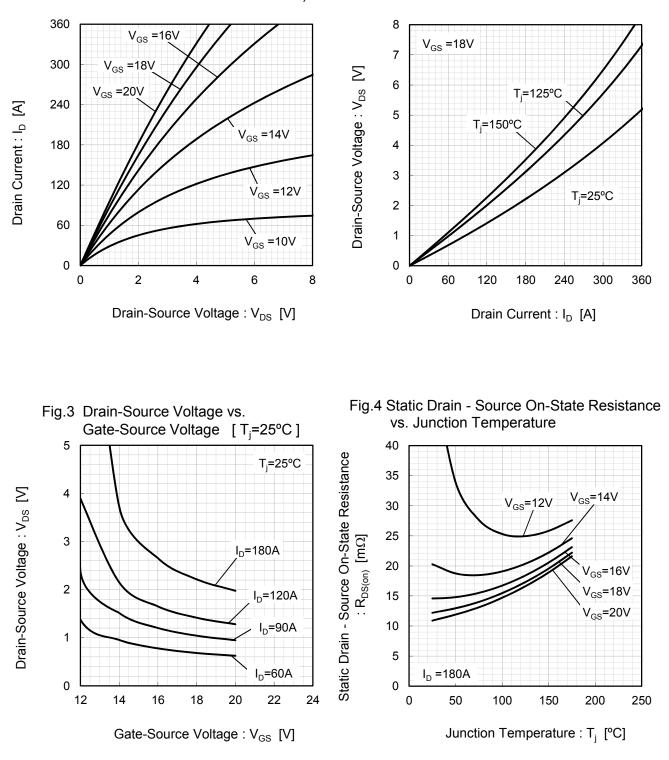


Fig.1 Typical Output Characteristics [ $T_j$ =25°C] Fig.2 Drain-Source Voltage vs. Drain Current

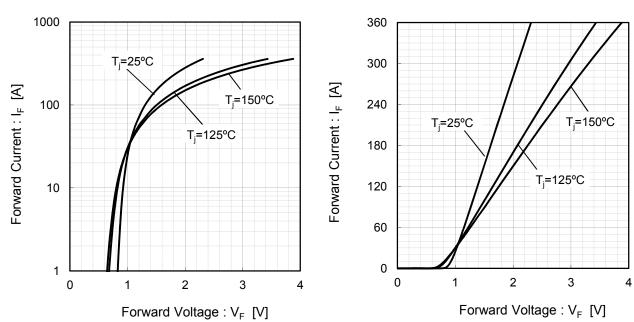
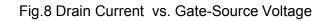
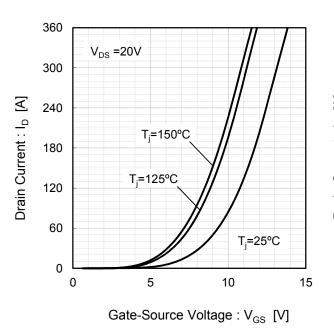


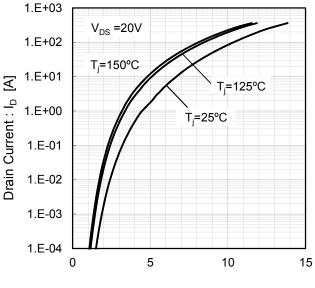
Fig.5 Forward characteristic of Diode

Fig.6 Forward characteristic of Diode

#### Fig.7 Drain Current vs. Gate-Source Voltage







Gate-Source Voltage :  $V_{GS}$  [V]

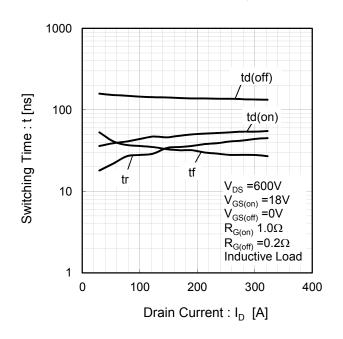


Fig.9 Switching Characteristics [T<sub>j</sub>=25°C]

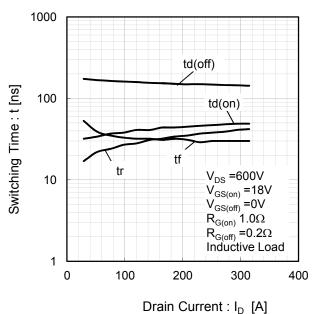
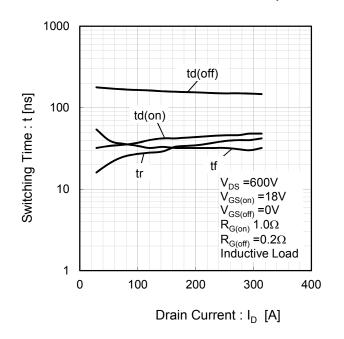
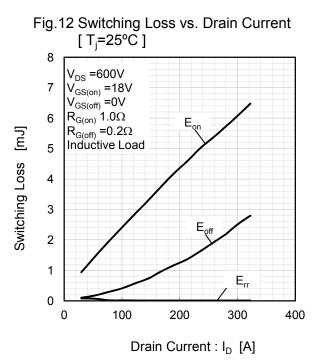


Fig.10 Switching Characteristics [T<sub>i</sub>=125°C]

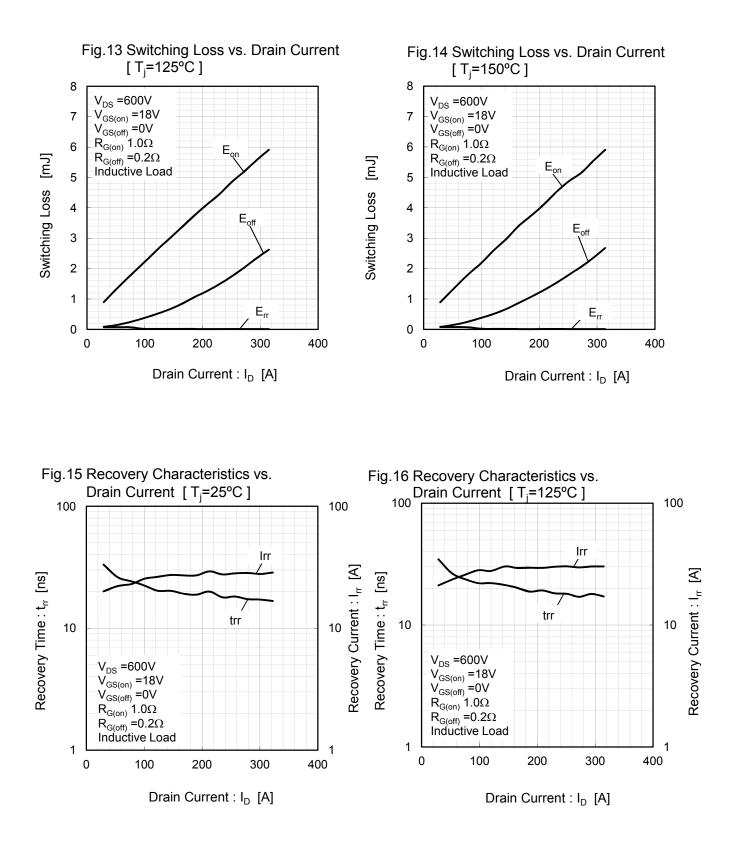


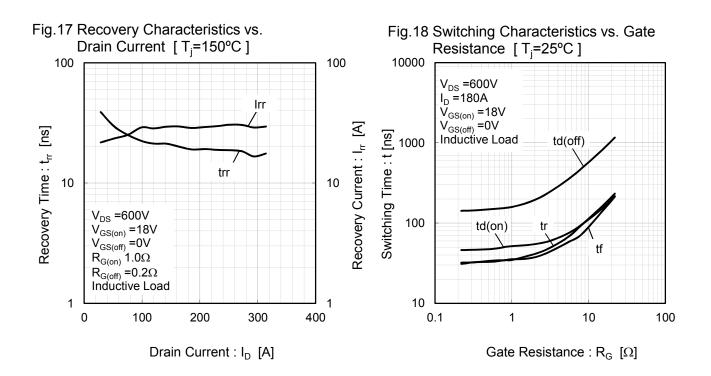
Fig.11 Switching Characteristics [T<sub>i</sub>=150°C]

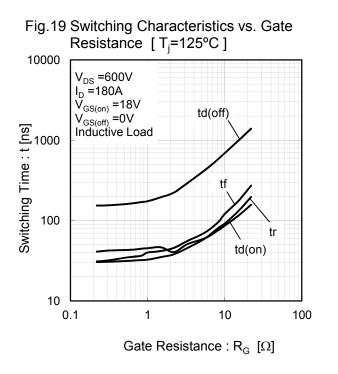


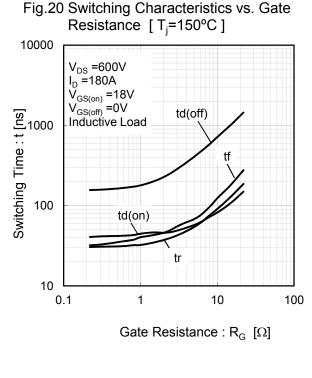


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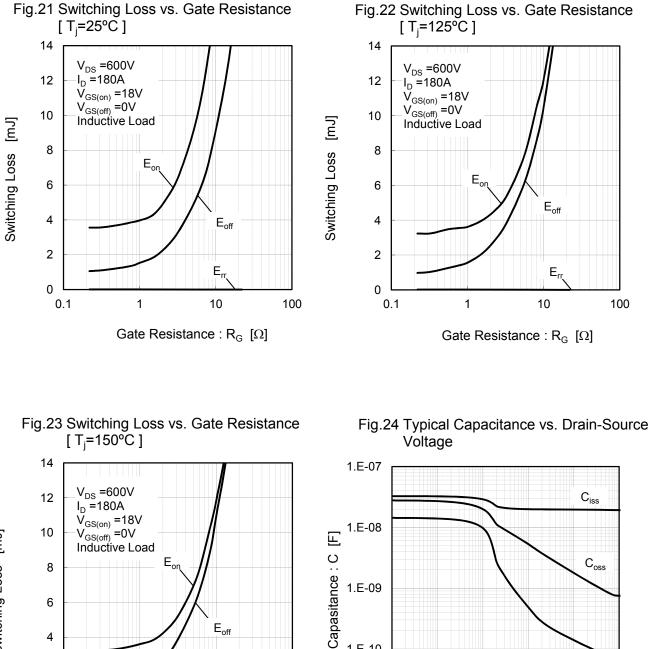






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## •Electrical characteristic curves (Typical)



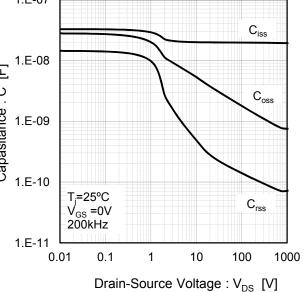


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0.1

1

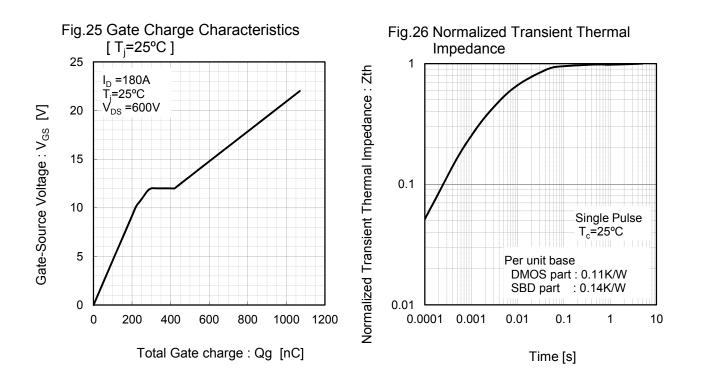


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10

Gate Resistance :  $R_G$  [ $\Omega$ ]





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Minimum Package Quantity	4
Packing Type	Corrugated Cardboard
Constitution Materials List	inquiry
RoHS	Yes